

SCHOTTKY DIE SPECIFICATION

TYPE: SB340

General Description: 40 V 3 A Standard VF

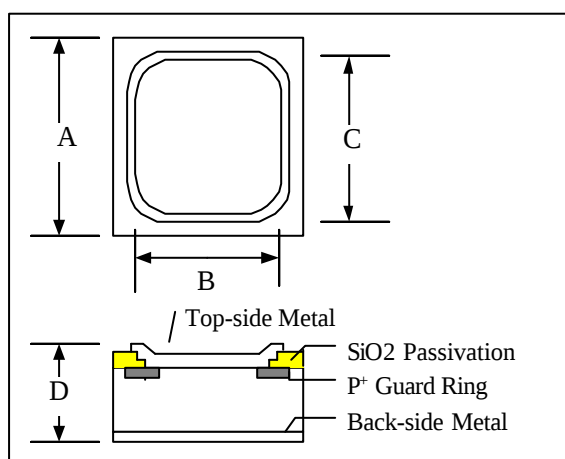
Single Anode

ELECTRICAL CHARACTERISTICS	SYM	Spec. Limit	Die Sort	UNIT
DC Blocking Voltage: $I_r=1\text{mA}$ (for wafer form)	VRRM	40	42.5	Volt
$I_r=0.5\text{mA}$ (for dice form)				
Average Rectified Forward Current	IFAV	3		Amp
Maximum Instantaneous Forward Voltage				
@ 3 Amperes, $T_a=25^\circ\text{C}$	VF MAX	0.5	0.49	Volt
Maximum Instantaneous Reverse Voltage				
$V_R=40\text{ Volt}$, $T_a=25^\circ\text{C}$	IR MAX	0.3	0.25	mA
Maximum Junction Capacitance @ 0V, 1MHZ	Cj MAX			pF
MAXIMUM RATINGS				
Nonrepetitive Peak Surge Current	IFSM	100		Amp
Operating Junction Temperature	T_j	-65 to +125		$^\circ\text{C}$
Storage Temperatures	TSTG	-65 to +125		$^\circ\text{C}$

Specification apply to die only. Actual performance may degrade when assembled.

MEMT does not guarantee device performance after assembly.

Data sheet information is subjected to change without notice.

DICE OUTLINE DRAWING


DIM	ITEM	μm^2	Mil ²
A	Die Size	1524	60.00
B	Top Metal Pad Size	1424	56.1
C	Passivation Seal	1444	56.9
D	Thickness (Min)	254	10
	Thickness (Max)	305	12

PS:

(1)Cutting street width is around 80um(3.14mil).

(2)Both of top-side and back-side metals are Ti/Ni/Ag